

## 10kV 100mA HIGH VOLTAGE DIODE

2CL2x is high reliability resin molded type high voltage diode in small size package which is sealed a multilayered mesa type silicon chip by epoxy resin.

### Features

- High speed switching
- High Current
- High surge resistivity for CRT discharge
- High reliability design
- High Voltage

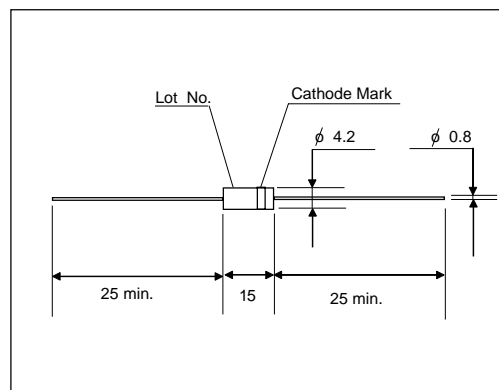
### Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

### Maximum Ratings and Characteristics

- Absolute Maximum Ratings

### Outline Drawings : mm



### Cathode Mark

| Type  | Mark |
|-------|------|
| 2CL2G |      |

| Items                                | Symbols   | Condition                                 | 2CL2G       | Units              |
|--------------------------------------|-----------|---|-------------|--------------------|
| Repetitive Peak Reverse Voltage      | $V_{RRM}$ |   | 10          | kV                 |
| Average Output Current               | $I_o$     | $T_a=25^{\circ}\text{C}$ , Resistive Load | 100         | mA                 |
| Surge Current                        | $I_{FSM}$ |   | 20          | $A_{peak}$         |
| Junction Temperature                 | $T_j$     |   | 155         | $^{\circ}\text{C}$ |
| Allowable Operation Case Temperature | $T_c$     |   | 125         | $^{\circ}\text{C}$ |
| Storage Temperature                  | $T_{stg}$ |   | -40 to +155 | $^{\circ}\text{C}$ |

- Electrical Characteristics ( $T_a=25^{\circ}\text{C}$  Unless otherwise specified)

| Items                         | Symbols  | Conditions  | 2CL2G | Units         |
|-------------------------------|----------|---|-------|---------------|
| Maximum Forward Voltage Drop  | $V_F$    | at $25^{\circ}\text{C}$ , $I_F = 100\text{mA}$              | 12    | V             |
| Maximum Reverse Current       | $I_{R1}$ | at $25^{\circ}\text{C}$ , $V_R = V_{RRM}$                   | 2.0   | $\mu\text{A}$ |
|                               | $I_{R2}$ | at $100^{\circ}\text{C}$ , $V_R = V_{RRM}$                  | 40    | $\mu\text{A}$ |
| Maximum Reverse Recovery Time | $T_{rr}$ | at $25^{\circ}\text{C}$                                     | -     | nS            |
| Junction Capacitance          | $C_j$    | at $25^{\circ}\text{C}$ , $V_R=0\text{V}$ , $f=1\text{MHz}$ | 15    | pF            |